	L #	Hits	Search Text	DBs	Time Stamp
1	L1	5631	(428/689,697,698,699, 704,539.5).CCLS.	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM TDB	2003/11/1 8 09:10
2	L2	3021	1 and (wear resistant erosion corrosion multilayer multi adj layer)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM TDB	2003/11/1 8 09:11
3	L3	3180	1 and (Ti titanium Zr zirconium TiN ZrN TiB ZrB)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM TDB	2003/11/1 8 09:12
4	L4	236	1 and ((ion) with(mix mixing mixed implant\$4 implantation))	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/11/1 8 09:14

	L #	Hits	Search Text	DBs	Time Stamp
5	L5	2640	1 and (carbide nitride boride)	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM TDB	2003/11/1 8 09:15
6	L6	260	1 and ((grade\$2 graduated gradient gradiant) near3 (layer sublayer multilayer coat\$4))	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2003/11/1 8 09:17
17	L7	337	2 and (3 or 5) and (4 or 6)	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM TDB	2003/11/1 8 09:18
8	L8	229	2 and (3 and 5) and (4 or 6)	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/11/1 8 09:51

	L #	Hits	Search Text	DBs	Time Stamp
9	L10	100	7 and(thickness thick depth) not 9	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM TDB	2003/11/1 8 09:20
10	L 9	224	8 and(thickness thick depth)	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/11/1 8 09:54
11	L11	3675	1 and (Hf hanium V vanadium Nb niobium Ta Tantalum Cr chromium Mo molybdenum W tungsten)	USPA T; US-P GPUB; EPO; DERW ENT; IBM_ TDB	2003/11/1 8 09:52
12	L12	251	2 and ((11 or 3) and 5) and (4 or 6)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2003/11/1 8 09:53

}	L #	Hits	Search Text	DBs	Time Stamp
13	L13	3695	1 and (Hf hafnium V vanadium Nb niobium Ta Tantalum Cr chromium Mo molybdenum W tungsten)	USPA T; US-P GPUB; IPO; DERW ENT; IBM TDB	2003/11/1 8 09:52
14	L14	251	2 and ((13 or 3) and 5) and (4 or 6)	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM TDB	2003/11/1 8 09:53
15	L15	22	14 and(thickness thick depth) not 8	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2003/11/1 8 09:54